

a first conductor structure and a second conductor structure formed on the substrate;

first sidewall spacers, each first sidewall spacer being formed to abut against both a side of the first or second conductor structures and a side of an insulator structure, the first sidewall spacers manifesting the self-aligned contact hole in the region between the first and second conductor structures; and

second sidewall spacers formed on sides of the first and second conductor structures opposite of the self-aligned contact hole.

Cont'd
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